NSN 5961-01-450-8229

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-450-8229 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Overall Diameter:** 0.145 inches **End Application:** Fuel system e/i fscm 76823 **Mounting Method:** Terminal **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 3.00 amperes all primaries and 5.00 amperes forward current, average absolute **Special Features:** Nuclear hardness critical process **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: